

Article

Discharge Characteristics and Plasma Erosion of Various Dielectric Materials in the Dielectric **Barrier Discharges**

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Abstract: The objective of this study is the investigation of dielectric barrier discharges (DBDs) with the solid plates and the flexible polymer films. A high capacitance with a high dielectric constant and a small thickness is responsible for the discharge of a high plasma current with a low operation voltage; here, the thin flexible polyimide film ensured a high capacitance, and is comparable to the thick solid-plate alumina. In the long-duration test of the dielectric-surface plasma erosion, the solid plates show a high resistance against the plasma erosions, while the polymer films are vulnerable to the etching by the plasma-species chemical reaction. The polymer-film surface, however, was reinforced remarkably against the plasma erosion by the silicone-paste coating.

Keywords: atmospheric pressure glow discharge; dielectric barrier discharge; dielectrics; silicon rubber; surface modification

1. Introduction

The nonthermal atmospheric-pressure plasmas (NTAPP) have been studied for their applications in the various fields of the ozone synthesis, surface modification, plasma chemistry, and biomedicine, including the skin cosmetics, skin diseases, and wound healing [1-10]. The NTAPP-using plasma jets and the dielectric barrier discharge (DBD) devices have been reported in the biomedical field [11–16]. A plasma jet is generated by the applying of a high voltage to the end electrode of the gas injector. The discharge gas in the plasma jets is used for various gases such as the inert gas [17-20], nitrogen gas (N_2) , air [12,21–25], and mixtures thereof [26–28]. In the DBD devices, the plasma is generated on the surface of the dielectric layer by the applying of a high voltage to the electrode enclosed in the dielectric layer. The two plasma types generated in the DBD devices are as follows: The human-skin floating electrode as the ground electrode [4,6], and the plasma generated in the dielectric layer corresponding to the high-voltage electrode around the ground electrode [29–32].

Since the first DBD experiments were reported by Siemens [7] in 1857, DBDs have been known for more than a century [33,34]. Quartz and alumina have been used as the dielectrics of the DBD devices [5–7]. The polymer film has also been considered for the DBD-device application. It is easy to handle the flexible polymer films regarding various geometric-structure forms due to their flexibilities. In addition, since the film dielectric layer is made as thinly as possible, the discharge voltage could be reduced, and this is advantageous for the DBD-device fabrication. Recently, the flexible polymer films have been used to manufacture a flexible plasma pad that can be applied for the wearable DBDs, such as the patches, bands, hats, and socks [35,36].



In this study, the discharge properties of various dielectric materials with thin solid plates and thin flexible films were examined regarding the DBD devices, with an especial focus on the plasma-discharge plasma erosion on the dielectric surface. The results of this study demonstrate that, for the DBD dielectric-layer application, the polymer films are vulnerable to the plasma erosion. The advantageous results of the reinforced silicone (Si) coating on the polymer films against the plasma erosion are described.

2. Materials and Methods

The glass, quartz, and alumina solid plates and the flexible polymer films were used as the dielectric materials for the experimental samples. The polyimide (PI), polypropylene (PP), and glass polymer (GP) were used as the dielectric materials of the flexible polymer films. Table 1 lists the information on the dielectric materials used in this experiment. Since the solid plates are fragile, they are limited to thickness reductions of less than several-hundred μ m. An alkaline earth boro-aluminosilicate wafer served as the glass in the experiment. Synthetic quartz was used in this study. The purity of the alumina-ceramic substrate is 99.9%. The thinnest solid plate among the commercially available ones is of the 500- μ m thickness (*T*). The dielectric constant *K* values are 9.0, 5.3 and 3.6 for the alumina, glass, and quartz, respectively. The selection of the samples of the flexible polymer film is based on the commercially available film thicknesses. For the PI, GP and PP, the *T* values are 125 μ m, 200 μ m and 300 μ m, respectively, while the *K* values are 2.8, 3.0 and 2.3, respectively. The *T* of the selected PI is the thickest among the commercial products. The GP film is equivalent to the smartphone-display protection film. In the flexible films, the dielectric thickness is different for each sample; accordingly, the capacitance (*C*~*K*/*T*) of each sample was affected by the *K* and *T* values.

(a)	Glass	Quartz	Alumina
(T, K)	(500 µm, 5.3)	(500 µm, 3.7)	(500 µm, 9.3)
Formula	B ₂ O ₃ -SiO ₂ -Al ₂ O ₃	SiO ₂	Al_2O_3
Trademark	Corning [®] EAGLE XG [™]	Corning [®] 7940 Fused Silica	-
(b)	Polyimide (PI)	Glass Polymer (GP)	Polypropylene (PP)
(T, K)	(125 µm, 3.4)	(200 µm, 3.0)	(300 µm, 2.3)
Formula		$\begin{array}{c c} & {}^{Ph} & {}^{O} & {}^{O} & {}^{Si} \\ Ph & {}^{O} & {}^{Si} & {}^{Ph} \\ & {}^{Si} & {}^{O} & {}^{Si} & {}^{Ph} \\ & {}^{O} & {}^{Si} & {}^{O} & {}^{Si} \\ & {}^{O} & {}^{Si} & {}^{O} & {}^{Si} \\ Ph & {}^{Si} & {}^{O} & {}^{Si} \\ & {}^{Ph} & {}^{Ph} \end{array}$	CH ₃
Trademark	Dupont—Kapton [®]	H&Global—SILPLUS [®]	-

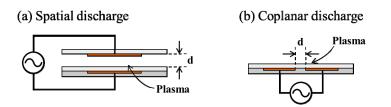
Table 1. Formula of dielectric materials: (a) Solid plates and (b) Flexible polymer films.

The PI-film properties include a high heat resistance, an excellent flexibility, and the resistance to chemicals and combustion [37]. The PI was developed for the aerospace industry in 1964 (DuPont Kapton[®]). The PI film cannot be deformed over a wide range of temperatures, ranging from -269 to 400 °C, but it has been widely used as the substrate of the flexible printed circuit board.

The PP is an inexpensive polymer material made of carbon (C) and hydrogen (H) [38–41] that is used in a variety of fields such as packaging films, fibers, and daily goods. The PP film is prone to oxidation (or degradation) when it is exposed to heat or the ultraviolet light. The PP melting point is approximately 160 °C, so it is considered thermally weak; however, its chemical properties are excellent. The PP can withstand many organic solvents, except strong oxidizing agents.

The GP has been developed to complement vulnerabilities such as the thermal deformation of the polymer materials. It is mainly used in the liquid-crystal protective films of the mobile phones and displays. In this experiment, the test sample film is SILPLUS[®] (H Global, Brooklyn, NY, USA).

In Figure 1, the various DBD types introduced in [33,34] were tested for the discharge-ignition experiments with the dielectric layer of the alumina-ceramic plate, as follows: spatial discharge between the face-to-face electrodes in (a), the coplanar discharge in (b), and the planar discharges between the both-side electrodes in (c-i)–(c-iv). The electrodes were coated with copper to 40-µm in thickness. All the experiments were performed in the atmospheric environment.



(c) Planar discharge between both-sided electrodes

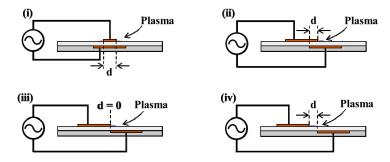


Figure 1. Schematic diagrams of the experiments with various dielectric barrier discharge (DBD) types in the atmospheric environment: (**a**) Spatial discharge between two parallel face-to-face electrodes; (**b**) coplanar discharge; and (**c**) planar discharges between both-side electrodes according to various arrangements at (**i**)–(**iv**).

In Figure 2, with the various dielectric materials listed in Table 1, a dielectric-barrier surface discharge was investigated for the discharge properties, current voltage, and firing voltage. The DBD structure shown in Figure 1c-iii was chosen, which is proper for the bio-medical application of the wearable plasma devices [35,36]. The plasma erosion of the dielectric surface was also tested. The damage and deformation on the dielectric surface were observed in a prolonged discharge test. The functional groups present in the infrared (IR) spectra of the PP- and PI-surface films in the absence or presence of the plasma were measured using the MB3000 Fourier transform IR spectroscopy device (ABB Bomen, Zurich, Switzerland).

Figure 2 shows the schematic diagram of the discharge experiment in the atmospheric environment. An annular-shaped ground electrode was attached to the dielectric upper surface, and a high-voltage circular-shaped electrode was attached to the lower surface. The electrodes were coated with copper (Cu) of the $T = 40 \mu m$. The outer and inner diameters of the annular-shaped electrode are 15 mm and 5 mm, respectively. The diameter of the circular-shaped electrode is 5 mm. The high-voltage electrode coincides with the ground-electrode inner circle. The high-voltage electrodes were insulated by the insulation pads attached onto the dielectric lower surface. A long-term discharge experiment was then conducted to assess the durability of the dielectrics.

A high voltage from 0.5 to 3.0 kV was applied to the electrodes with the direct current (dc)–alternating current (ac) inverter. The voltage is the sinusoidal signal with the frequency of 40 kHz. The high voltage was measured using the P6015A high-voltage probe (Tektronix, Beaverton, OR, USA), and the current was measured using the Tektronix P6022A ac probe. The voltage and current signals were observed using the Tektronix DPO 4034 digital oscilloscope. All the data of current and voltage are expressed as the root-mean-square (rms) value in all the experiments.

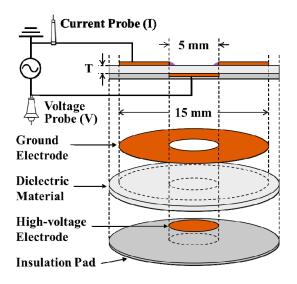


Figure 2. Schematic diagram of the planar-discharge experiments performed in the atmospheric environment with the various dielectric materials listed in Table 1.

3. Results and Discussion

From the discharge experiments shown in Figures 1 and 2, the resultant discharge properties are presented in Section 3.1, the dielectric-surface plasma erosion is described in Section 3.2, and the plasma-erosion analysis is in Section 3.3.

3.1. Discharge Characteristics

The ignition (electric-breakdown or discharge-firing) test is presented in Figures 3 and 4, while the electrode arrangements of the planar DBDs are shown in Figure 1 with the alumina dielectric plate. The gap distance is an essential parameter for the ignition along the discharge path between the metallic electrodes on the surface of the dielectric layer. Figures 5 and 6 with the various dielectric materials listed in Table 1 show the discharge mode and the current–voltage (I–V) characteristics, respectively, while the DBD structure of Figure 2 is applicable for the actual plasma pads [35,36].

For the DB discharge between the face-to-face electrodes in Figure 1a, Figure 3 shows the spatial-discharge photographs in (a) and the Paschen curve in (b) according to the spatial gap distance *d* between the upper electrode and the dielectric-layer surface. The dielectric layer is the alumina ceramic with the T = 0.5 mm in thickness and the copper electrodes are W = 10 mm in width and L = 30 mm in length. The upper electrode was applied to a high voltage and the lower electrode was grounded. For the discharge ignition with the proposed-inverter output voltage in the range of 0.5–3.0 kV, the *d* of this experiment is from 0.1 to 0.5 mm. The firing voltage $V_f = 0.99-1.76$ kV corresponding to the d = 0.1-0.5 mm and the Pd = 7.7-38.0 (Torr cm) for the P = 760 Torr. The firing voltage V_f and the current were measured three times and averaged within an error range of less than 5%, and the firing voltage was plotted in Figure 3b. The data of the gap distance, firing voltage, and current are (d, V_f , I) = (0.1 mm, 0.99 kV, 5.5 mA), (0.2 mm, 1.16 kV, 4.7 mA), (0.3 mm, 1.35 kV, 4.5 mA), (0.4 mm, 1.53 kV, 4.4 mA), and (0.5 mm, 1.76 kV, 4.2 mA). As the *d* was increased, the V_f increased for the Paschen breakdown while the current decreased, even for the increasing of the brightness intensity of the visual plasma.

Considering the decreasing current, the amount of the displacement current that can be passed through the dielectrics and the real current (plasma current other than the capacitive type) were determined. It was expected the displacement current would be high for the high capacitance of the short gap, and therefore the total current increased to a high value for the short gap, while the total current for the long gap is low, even though it was expected the plasma current would be high with the high V_f for the long gap. From the Paschen data of Figure 3b, it can be interpolated that the V_f is

~21 kV for the d = 1 cm, together with the reported operating voltage of the same order as that of the earlier atmospheric DBD experiments where the *Pd* is ~760 Torr cm [33,34].

In the coplanar discharge of Figure 1b, which is the typical structure of the microdischarge in the plasma display panel (PDP), the ignition was not observed with the alumina plate of the T = 0.5 mm in this experiment. With the proposed inverter in the output-voltage range of 3 kV, the insulation breakdown occurred between the two electrodes of the short gap d < 1 mm, and the ignition on the dielectric-layer surface did not occur for the d > 1 mm. As a result, the coplanar discharge cannot be ensured unless the dielectric layer is quite thin. In the case of the microdischarge PDP with the dielectric-layer thickness of less than 100 µm, the reported ignition voltage is approximately 300 V for the low-pressure values of less than a few tens of Torr. Therefore, the DBD atmospheric discharge is not suitable for the coplanar discharge.

The ignition tests with the planar discharge of Figure 1c are shown in Figure 4. Two electrodes are both sides of the dielectric layer (alumina ceramic) with the T = 0.5 mm. A high voltage was applied to the lower electrode covered with the insulation pad, and the ground was applied to the upper electrode. All the electrodes are 10-mm wide and 30-mm long, except the upper electrode of the 5-mm width, as shown in Figure 4a. All the data of ignition voltage V_f and current were measured three times and averaged as shown in Figure 4a–d and as plotted in Figure 4e within an error range of less than 5%. The negative value of gap distance d means the overlapped electrode. The upper electrode is overlapped as d = -5 mm over the center of the lower electrode in Figure 4a, where the $V_f = 1.0$ kV and the current is I = 5.3 mA for both the plasma-generated upper-electrode sides. In Figure 4b with the overlapped electrodes of d = -2 mm at the edge, the $V_f = 1.1$ kV and the current is I = 2.3 mA. In Figure 4c with the d = 0 between the two electrodes, the ignition voltage is $V_f = 1.2$ kV and the current is I = 1.4 mA. In Figure 4d with the d = 2 mm, the $V_f = 2.2$ kV and the current is I = 1.8 mA. With the overlapped electrodes of (a) and (b), the V_f is low while the current is high, since the displacement current is high for the high capacitance between the overlapped electrodes. Comparing the d = 0 in (c) with the d = 2 mm in (d), the V_f for the d = 2 mm is approximately two times higher than that for the d = 0. Further, for the wide-gap distance of d = 2 mm in (d), the discharge is unstable and the plasma is nonuniform on the discharge surface. With the wider d of > 3 mm, the ignition will not occur in the range of 3 kV with respect to the proposed inverter power system. Therefore, the d = 0 is proper in terms of the planar DBD. Thus, the structure of Figure 1c-iii was chosen for the following experiment, shown in Figure 2, for the bio-medicine application.

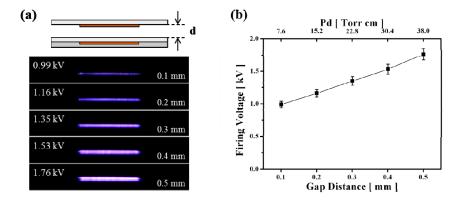
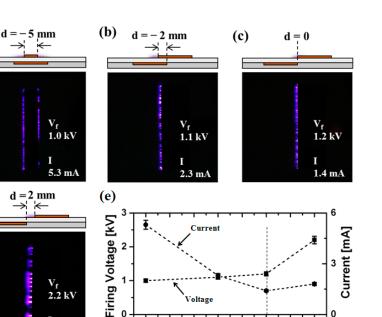


Figure 3. Cross-sectional pictures of the spatial discharge at the ignition voltage (V_f) according to the gap distance (d) with the dielectric barrier discharge (DBD) structure shown in Figure 1a in (**a**) and the Paschen curve with the firing voltage (V_f) versus the d in (**b**).

(a)

(d)



-3 -2 -1 0

Gap Distance d [mm]

-4

0

2

Figure 4. Pictures of the planar discharge on the dielectric surface at the ignition voltage (V_f) in the dielectric barrier discharge (DBD) structure of Figure 1c with the both-side electrodes: overlapped 5 mm at the center in (a), overlapped 2 mm at the edge in (b), no gap distance (d) = 0 in (c), and d = 2 mm in (d). And the graph of firing voltage and current versus the gap distance d in (e) where the negative value of gap distance d means the overlapped electrodes.

1

0

-5

Π

1.8 mA

In Figures 3–5, the shape of the discharge mode represents the multichannels of the streamer discharge that typically appear in the DBD [33,34]. Figure 5 shows the photographs of the discharges on the surface of the glass sample of Table 1 from the experiment shown in Figure 2. The plasma generation occurred on the dielectric surface over the high-voltage electrode with the 5-mm diameter. As shown in Figure 5a, the plasma was generated at the boundary line between the high-voltage and ground electrodes. As the current and voltage were increased, the plasma was observed throughout the overall boundary of both the electrodes, as shown in Figure 5b,c. The discharge was gradually enlarged to the center of the surface of the high-voltage electrode, as shown in Figure 5d,e.

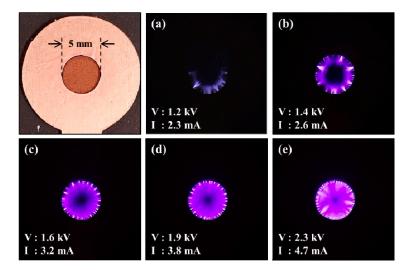


Figure 5. Photographs of the discharge shapes in the dielectric barrier discharge (DBD) structure of Figure 2 in (a-e) with the increasing current and voltage on the glass-plate surface.

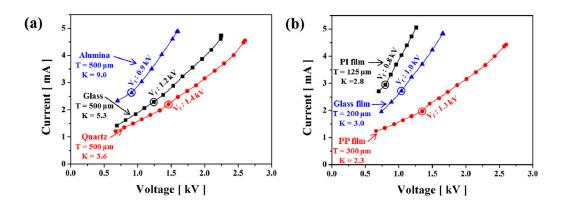


Figure 6. Current-voltage (I-V) graphs for the solid plates (a) and polymer films (b).

Figure 6 presents the typical I–V characteristics, the so-called *filamentary mode* [33,34,42,43], in terms of the typical DBD operation with the atmospheric pressure. Since the capacitance is so high between the two short-gap electrodes on the surface of the both-side dielectric layer, a high displacement current is expected even before the ignition with an operation voltage less than the V_f . At the breakdown, the plasma current that is due to the filamentary channels of the microdischarges is added to the displacement current; however, the plasma current is restricted by the dielectric layer and the current will not rise abruptly. Thus, at the V_f , the slightly increasing current slope reflects the plasma generation. Under the special operating conditions, usually those of a low-pressure operation, the *glow mode* is present [42,43]. The latter cases of the I–V characteristics have been analyzed regarding the usual discharge-tube experiments, including the DBD structure with the gases of a low pressure that is approximately several tens of Torr [44–47]. At the breakdown voltage, the electron avalanche is accompanied by the Townsend discharge, which is the abrupt current increase followed by the normal glow in terms of the I–V characteristics. Regarding the DBD experiments of Figures 3–5, however, the representation of the filamentary mode of the streamer channel is shown in Figure 6.

Figure 6 shows the I–V curves of each dielectric sample listed in Table 1 with respect to the discharge experiment shown in Figure 2. Figure 6a shows the graph of the solid plates and Figure 6 (b) shows the graph of the flexible films. For the electrode structure in Figure 2 with the thickness of each dielectric listed in Table 1, the capacitance was measured using the LCR-821 LCR meter (GW Instek, Taiwan), and the following results were given: (alumina, glass, quartz) = (2.40, 2.20, 1.70 pF), and (PI, GP, PP) = (2.55, 2.32, 1.70 pF). The firing voltage (V_f) is represented in the graph of Figure 6. For the voltage was selected upon the initial observation of the plasma with the naked eye. For all the solid plates and flexible polymer films, the larger *C* values correspond to the greater reductions of the firing voltage and the plasma current.

For the analysis of the I–V graphs of Figure 6, the equivalent circuit is presented in Figure 7. Two circuit paths were used for the I–V measurement, as follows: One is the capacitor (C_o) circuit between the electrodes of the upper and lower plates, and the other is the circuit connecting the dielectric-layer capacitance (C_1) and the plasma resistance (R_p). The equivalent circuit shown in Figure 7 is composed of a parallel connection with two circuits. The impedance (Z) of the two parallel circuits is as follows [48,49]:

$$\frac{1}{Z} = j\omega C_o + \frac{1}{R_p + (1/j\omega C_1)}$$
(1)

The slope of the I–V curve in Figure 6 corresponds to the |1/Z| of Equation (1). Assuming the sufficient largeness of the R_p ($R_p > |1/\omega C_1|$), and without considering the imaginary capacitance, the slope of the I–V curve is as follows:

$$|1/Z| \approx \sqrt{\omega^2 C_o^2 + (1/R_p^2)}$$
 (2)

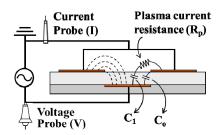


Figure 7. The equivalent circuit of the current-voltage measurement.

In the I–V curve of Figure 6, the slope tends to change slightly before and after the discharge. The slope slightly increased after the discharge. This finding means the slope of Equation (2) increased as the R_p decreased due to the post-discharge current increase. Using Equation (2) with the reactance of the C_o , the R_p was calculated for the slope value of the I–V curve in Figure 6 for each dielectric sample. The reactance ($X_o = 1/\omega C_o$) with the LCR-meter-measured C_o values was calculated as follows: (alumina, glass, quartz) = (1.84, 1.90, 2.47 MΩ) and (PI, GP, PP) = (1.78, 1.87, 2.47 MΩ). Using the X_o , the R_p before and after the discharge was calculated by the comparison of the slope of the I–V curve in Figure 6 with the |1/Z| of Equation (3). The calculated pre-discharge R_p values of each sample are as follows: (alumina, glass, quartz) = (527, 680, 920 kΩ) and (PI, GP, PP) = (294, 441, 1053 kΩ). The post-discharge R_p values were reduced, as follows: (alumina, glass, quartz) = (313, 407, 490 kΩ) and (PI, GP, PP) = (217, 298, 536 kΩ).

According to the result of the equivalent-circuit analysis, the slope of the I–V curve was given by Equation (2) as $|1/Z| \approx \omega C_0$ in the low-current region before the discharge. However, after the discharge, it presented the high-current region where the R_p decreased as the slope was increased. The capacitive reactance ($X_c = 1/\omega C_0$) at the low current (2–3 mA) before the discharge is several M Ω . The R_p is in the range from several-hundred k Ω to M Ω . After the discharge, the R_p became as low as several-hundred k Ω with the current values of more than 3 mA. This R_p is in the order of several-hundred k Ω for the DBD discharge with the discharge voltage of approximately 1 kV and the current of several mA.

3.2. Plasma Erosion on the Dielectric Surfaces

Figure 8 shows the surface degradation of the dielectric samples during the prolonged operation. Figure 8a shows an enlarged photograph of the post-discharge solid-plate surface. The dotted line of the photograph shows the boundary line between the high-voltage electrode and the ground electrode. The surface was damaged on the inner surface of the dotted line due to the plasma generation. The operating-condition current of each solid plate is approximately 3 mA (V = 1.0 kV for alumina, V = 1.6 kV for glass, and V = 2.0 kV for quartz), as shown in the graph of Figure 6a. The damage on the solid-plate dielectric surface is barely apparent, even after the long operating run of 10 h. A very clean solid-plate surface was maintained after the discharge, even for the alumina, showing a slight yellow discoloring on the plasma-generation boundary surface. The solid plates, however, did not show the dielectric breakdown or the surface degradation.

Figure 8b is an enlarged photograph of the polymer-film surface after the long-run discharge. The operating-condition current of the polymer-film sample is also approximately 3 mA, as shown in Figure 6b, where the operating voltage is 0.9 kV for the PI, 1.2 kV for the GP, and 2.0 kV for the PP. On the surface of the polymer film, a severe plasma-erosion was observed. The plasma erosion caused persistent damage on the film surface and the dielectric breakdown on the damaged surface. After 19 min of the PP-film discharge operation, the dielectric breakdown occurred and the film-surface damage was observed. The erosion pattern on the PP-film surface is deep and clear. The PP film is vulnerable to the surface damage and the dielectric breakdown since the PP heat resistance is low.

The dielectric breakdown occurred in the PI film after 30 min of the operation. The pinhole appeared due to the dielectric breakdown on the PI film. The GP film did not show the dielectric breakdown even after the operation lasted for more than 10 h; however, a slight crack and the plasma erosion were also observed on the GP surface.

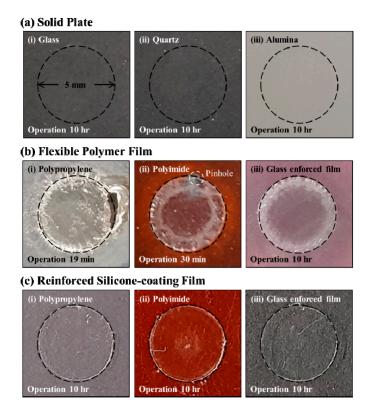


Figure 8. Surface pictures of the solid plates after the extended-run operation (**a**), the flexible polymer films (**b**), and the reinforced-silicone (Si)-coating films (**c**) after the 10-h operation at the current of approximately 3 mA.

For the purpose of preventing the plasma erosion in Figure 8c, the polymer film was reinforced by the Si-paste coating on the film surface. The KE-441K Si paste (Shinetsu, Tokyo, Japan) was used. Since the Si chemical resistance is high, the coating prevents the plasma degradation and erosion and enhances the durability of the flexible polymer film, even for the PP film. On the surface of the polymer films coated with the Si paste of the thickness of approximately 40 μ m, the erosion and dielectric breakdown did not occur, even after the long-run 10-h operation, as shown in Figure 8c. In the case of the Si-coated polymer films, however, the film surfaces were not degraded even after 10 h of the operation.

3.3. Plasma-Erosion Analysis

In the long-time discharge test results of Figure 8, the PP failed even for the short-time operation of approximately 19 min; the PI withstood 30 min of the operation. However, the Si-reinforced films did not show the plasma erosion. The weakness of the polymer films against the plasma erosion might be affected by the chemical reaction to the air plasmas. It is currently unclear whether the plasma erosion ensures the structural change of the polymer chain. The etched patterns on the film surfaces, however, seem to be due to the chemical reactions with the plasma ions and radicals.

To explicate the damages of the polymer film-surface, the IR spectroscopy was performed [50,51]. Prior to the experiments, the film to be measured was completely dried. The spectra were recorded in the range from $4500-500 \text{ cm}^{-1}$ with the spectral resolution of 1.0 cm^{-1} . Each spectrum is the average of 16 scans with the detector gain of 1.00.

The IR spectra of the PP-surface film in the absence or presence of the plasma discharge are shown in Figure 9. The new absorption bands of the damaged-PP film that are between 1720 and 1580 cm⁻¹ might be due to the C=C and C=O stretching vibrations and the CH bending vibrations. The broad band at approximately 1720 cm⁻¹ is related to the C=C and C=O stretching vibrations [51]. From these new absorption bands of the damaged-PP film compared with those of the original PP-surface film in Table 1, the structural change of the PP chain could be due to the plasma discharge on the PP film, as shown in Figure 10.

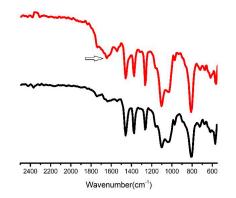


Figure 9. Infrared (IR) spectra of the original polypropylene (PP) surface (lower black line) and the PP surface with the plasma discharge (upper red line).

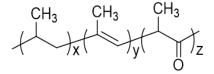


Figure 10. Proposed structure of the polypropylene (PP) chain changed by the plasma discharge from the original PP structure, as shown in Table 1.

To explicate the damages of the PI-film surface, the IR spectroscopy was performed, and the results are shown in Figure 11. The IR spectra of the PI-surface film in the absence or presence of the plasma discharge are shown. There were no new absorption bands regarding the PI-surface film with the plasma discharge compared with the original PI-surface film, as shown in Figure 11. This finding suggests that the structural change of the PI with the plasma discharge is not due to the rigid polymer back-bond structure such as the aromatic heterocyclic ring in the polymer main chain.

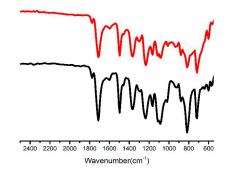


Figure 11. Infrared (IR) spectra of the original polyimide (PI) surface (lower black line) and the PI surface with the plasma discharge (upper red line), showing no structural change after the plasma discharge.

In addition, there were no new absorption bands regarding the reinforced-Si-coating PI films with the plasma discharge compared with the original reinforced Si film, as shown in Figure 12. This finding suggests the absence of a chemical structural change of the reinforced-Si-coating PI films with the plasma discharge, due to the high chemical resistance and stability of the Si.

From the IR-spectra results, the PP-chain structure was changed; however, that of the PI or the Si film was not changed. The PP was severely eroded by the surface plasma. The PI was also damaged by the plasma. The Si film, however, strongly resisted the plasma erosion.

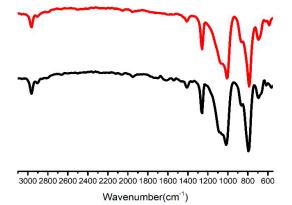


Figure 12. Infrared (IR) spectra of the original silicone (Si) film (lower black line) and the Si PI-surface film with the plasma discharge (upper red line).

The erosion phenomena of the dielectric-film surfaces are considered according to the chemical and physical reactions of the plasma ions and radicals. In Figure 8 of the long-time discharge, the solid-plate surfaces were not damaged while the polymer-film surface showed the etched patterns. Regarding the ion-bombardment sputtering, the threshold ion energies in the range of 10–30 eV are evident for the physical sputtering [52]. These ion energies are not available since the electron and ion plasma energies of this experiment of the atmospheric-pressure discharge are in the order of 1 eV and 0.01 eV, respectively. The oxygen and nitrogen atmospheric plasmas, however, can readily chemically affect the polymer surface of the organic materials, rather than that of the inorganic solid dielectrics. Thus, the polymers can be easily etched away by the *reactive oxygen and nitrogen species* (RONS) in the atmospheric-pressure plasma discharge, while the oxide materials such as silica (SiO₂) and aluminum oxide (Al₂O₃) are quite stable against the RONS. Therefore, the chemical reactions rather than the physical sputtering exerted the effects on the surface degradation.

4. Conclusions

The main parameter of the various dielectric materials for the DBD devices is the capacitance, $C \propto K/T$, with the dielectric constant, K, and the thickness, T. The characteristic of the current–voltage (I–V) depends on the C, which is proportional to the slope of the I–V curve. A large C of a high K and thin T provides a low firing voltage and a high amount of the plasma current. For the solid plates with the T of 500 µm, the K of the ceramic alumina is 9.0, which is larger than that of the glass (K = 5.3) or quartz (K = 3.6). The K of the thin flexible polymer films is $\approx (2\sim3)$, which is smaller than those of the solid plates. Since the solid plates are fragile, they are limited to the thickness reduction of less than a few-hundred µm. Alternatively, the commercialized polymers are available to form the thin films with the T of less than 100 µm and with a high C, and this is achieved by reducing the film T. Therefore, the C = 2.55 pF with the K = 2.8 and the T = 125 µm is comparable to that of the alumina with the C = 2.40 pF, the K = 9, and the T = 500 µm.

In the prolonged tests involving the discharge samples, the solid plates remained strong against the plasma erosion, while the polymer films were readily etched by the chemical reaction of the air-plasma species. The glass polymer (GP) film is somewhat stronger than the polymer film; however, its film surface was also damaged after the long-run test of 10 h. The polyimide (PI) shows the dielectric breakdown and the surface degradation after the 30-min operation. The plasma erosion of the polypropylene (PP) is serious; its film did not withstand the damage even after the short-time operation of approximately 19 min. In the IR spectra of the polymer films, the structural change pf the PP chain was observed due to the plasma; however, such a change was not found for the PI. The films coated with the Si were reinforced, and they hardly showed any plasma-erosion damage, even after the prolonged test that lasted for more than 10 h.

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